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| IN THE UNITED STATES PATENT AND TRADEMARK OFFICE | |
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| In re application of: Marwan H. Khater, et al. | Date: August 11, 2005 |
| Serial Number: 10/709,222 | Examiner: Joseph H. Nguyen |
| Filed: 4/22/04 | Group Art Unit: 2815 |
| Title: Structure and Method of Forming a Bipolar Transistor Having a Self-Aligned Raised Extrinsic Base Using Link-Up Region Formed From an Opening Therein | IBM Corporation D/18G, B/300, Zip 482 2070 Route 52 Hopewell Junction, NY 12533-6531 |

AMENDMENT UNDER RULE 312

Mail Stop: Issue Fee
Commissioner of Patents and Trademarks
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Responsive to the Notice of Allowance mailed July 1, 2005, please amend the application as follows: